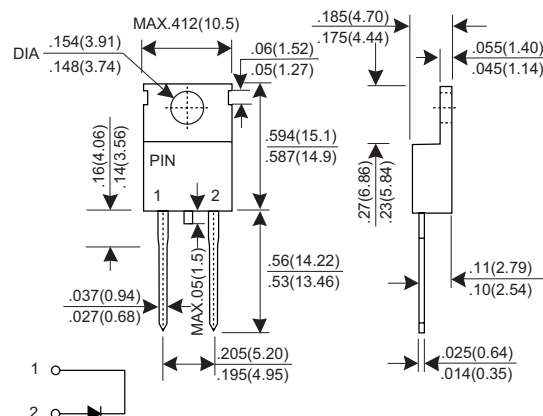


COMCHIP
SMD DIODE SPECIALIST

Features

- ★ Fast switching for high efficiency
- ★ Low forward voltage drop
- ★ High current capability
- ★ Low reverse leakage current
- ★ High surge current capability

TO-220AC



Dimensions in inches and (millimeters)

- ★ Case: Molded plastic TO-220AC
- ★ Epoxy: UL 94V-0 rate flame retardant
- ★ Terminals: Solderable per MIL-STD-202 method 208
- ★ Polarity: Color band denotes cathode
- ★ Mounting position: Any
- ★ Weight: 2.03 grams

For capacitive load, derate current by 20%.

	SYMBOL	SF 8A01-G	SF 8A02-G	SF 8A03-G	SF 8A04-G	SF 8A05-G	SF 8A06-G	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	300	400	600	V
Maximum RMS Voltage	VRMS	35	70	140	210	280	420	V
Maximum DC Blocking Voltage	VDC	50	100	200	300	400	600	V
Maximum Average Forward Rectified Current Tc=100°C	IF(AV)	8.0						A
Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)	IFSM	125						A
Maximum Instantaneous Forward Voltage @ 8.0 A	VF	0.95			1.3		1.5	V
Maximum DC Reverse Current @TJ=25°C At Rated DC Blocking Voltage @TJ=125°C	IR	10.0 250						uA uA
Maximum Reverse Recovery Time (Note 1)	Trr	35			50			nS
Typical junction Capacitance (Note 2)	CJ	65						pF
Typical Thermal Resistance (Note 3)	RθJC	2.2						°CW
Operating Junction and Storage Temperature Range	TJ, TSTG	-55 to + 150						°C

NOTES : (1) Reverse recovery test conditions $I_F = 0.5A$, $I_R = 1.0A$, $I_{rr} = 0.25A$.
(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.
(3) Thermal Resistance junction to case.

RATINGS AND CHARACTERISTIC CURVES SF8A01-G THRU SF8A06-G

FIG.1 - FORWARD CURRENT DERATING CURVE

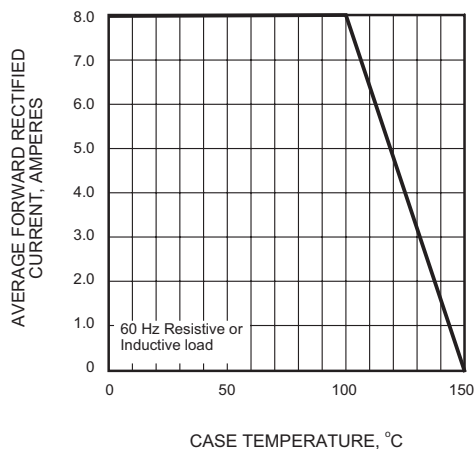


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

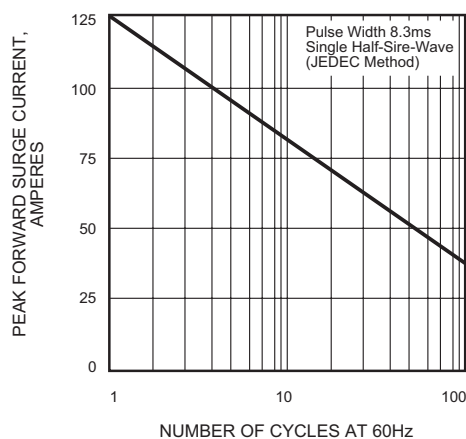


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

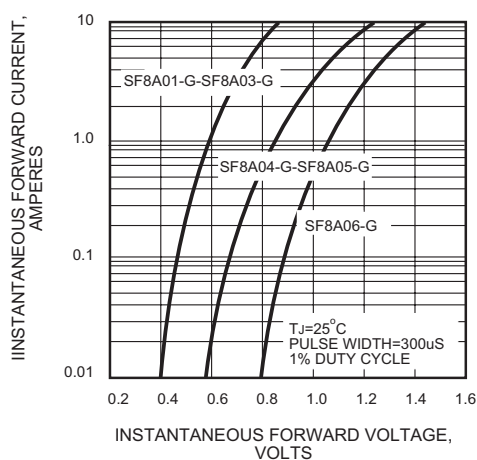


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

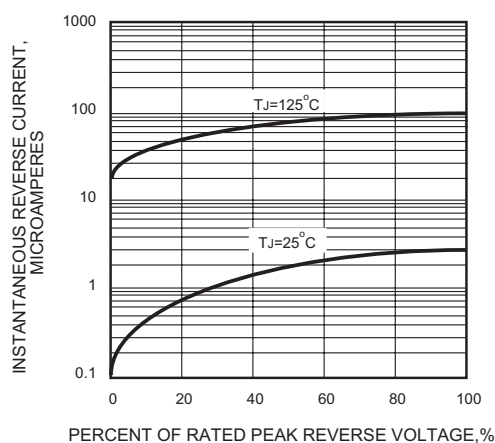


FIG.5 - TYPICAL JUNCTION CAPACITANCE

